



CENTIGRID® ESTABLISHED RELIABILITY MILITARY DPDT CMOS COMPATIBLE



SERIES	RELAY TYPE
116C	DPDT general-purpose relay with internal power MOSFET driver, Zener diode gate protection, and diode coil suppression

DESCRIPTION

The 116C Centigrid® relay is an ultraminiature, hermetically sealed, armature relay capable of being directly driven by most IC logic families. Its low profile height and .100" grid spaced terminals, which preclude the need for spreader pads, make it ideal for applications where extreme packaging density and/or close PC board spacing are required.

The basic concept and internal mechanical structure are similar to the 114 DPDT relay. The following unique construction features and manufacturing techniques provide overall high reliability and excellent resistance to environmental extremes:

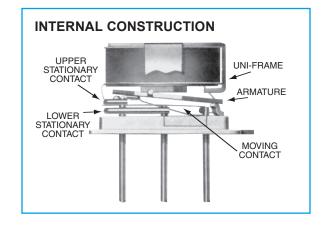
The 116C feature:

- · All welded construction.
- Advanced cleaning techniques provide maximum assurance of internal cleanliness.
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity.
- · High force/mass ratios for resistance to shock and vibration.
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities.

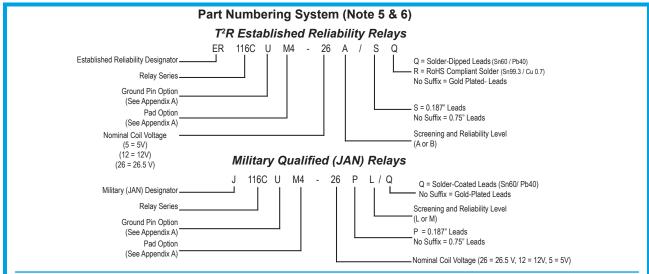
By virtue of its inherently low intercontact capacitance and contact circuit losses, the 116C relay has proven to be an excellent ultraminiature RF switch for frequency ranges well into the UHF spectrum. A typical RF application for this Centigrid® relay is in handheld radio transceivers, wherein the combined features of good RF performance, small size, low coil power dissipation and high reliability make it a preferred method of Transmit-Receive switching.

The Series 116C utilizes an internal silicon diode for coil suppression, a Zener diode to protect the MOSFET gate input, and an N-channel enhancement mode MOSFET chip, which enables direct relay interfacing with most Microprocessor and IC logic families (CMOS, TTL and MOS).

ENVIRONMENTAL AND PHYSICAL SPECIFICATIONS			
Temperature (Ambient)	–65°C to +125°C		
Vibration (Note 1)	30 g's to 3000 Hz		
Shock (Note 1)	75 g's, 6ms half sine		
Acceleration	50 g's		
Enclosure	Hermetically sealed		
Weight	0.11 oz. (3.12g) max.		
Reflow Temperature	260°C max. temp. 1 min. max		







GENERAL ELECTRICAL SPECIFICATIONS (-65 °C to 125 °C unless otherwise noted. See notes 2 & 3.)

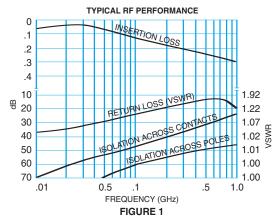
Contact Arrangement		2 Form C (DPDT)		
Rated Duty		Continuous		
Contact Resistance		0.1 ohm max. before life; 0.2 ohm max. after life at 1A/28Vdc		
Contact Load Rating	(DC)	Resistive: 1 A/ 28 Vdc Inductive: 200 mA/ 28 Vdc (320mH) Lamp: 100 mA / 28 Vdc (320mH) Low level: 10 to 50 μA @ 10 to 50 mV		
Contact Load Rating	(AC)	Resistive: 250 mA / 115Vac, 60 and 400 Hz (Case not grounded) 100 mA / 115 Vac, 60 and 400 Hz (Case grounded)		
Contact Life Ratings		10,000,000 cycles (typical) at low level 1,000,000 cycles (typical) at 0.5 A / 28 V _{dc} resistive 100,000 cycles min. at all other loads specified above		
Contact Overload Rat	ing	2 A / 28 V _{dc} Resistive (100 cycles min.)		
Contact Carry Rating		Contact Factory		
Operate Time		2.5 ms max. at nominal rated coil voltage		
Release Time		1.5 ms max.		
Contact Bounce		1.5 ms max.		
Intercontact Capacita	nce	0.4 pf typical		
Insulation Resistance	•	10,000 M Ω min. between mutually isolated terminals		
Dielectric Strength (V	_{rms} /60 Hz)	Atmospheric pressure: 500 70,000 ft: 125		
Negative Coil Transie	nt (Vdc)	1.0 Vdc Max.		
Diode P.I.V. (Vdc)		100 Vdc Min.		
Zamar Valtaga (V.)	Min.	17		
Zener Voltage (Vdc) Max.		23		
Zener Leakage Current (μA at 15.2 Vdc) (max.)		2.5		
Power FET Characteristics (Vdc, Max.)	Turn Off Gate Voltage	0.5		
	Turn On Gate Voltage	3.8 (Note 4)		
	Drain-Source Voltage	55		

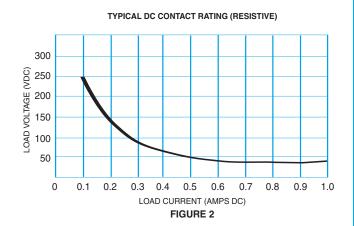


DETAILED ELECTRICAL SPECIFICATIONS (-65 °C to 125 °C unless otherwise noted. See notes 3.)

BASE PART NUMBERS (116C)		116C-5	116C-12	116C-26
Coil Voltage	Nom.	5.0	12.0	26.5
	Max.	5.6	16.0	32.0
Coil Curent	Max.	132.3	36.1	19.9
(mAdc@25°C)	Min.	96.5	24.9	12.9
Coil Operating Power (mW, nominal)	641	369	450
Pick-up Voltage (Vdc, Max) (Note 4)		4.0	9.8	19.5
Gate Pick-up Voltage	Min.	0.13	0.36	0.72
(Vdc) (Note 4)	Max.	2.3	6.5	13.0

PERFORMANCE CURVES (Note 2)



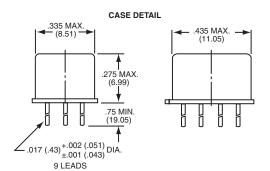


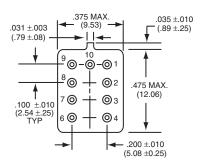
NOTES:

- 1. Relay contacts will exhibit no chatter in excess of 10 μs or transfer in excess of 1 μs .
- 2. "Typical" characteristics are based on available data and are best estimates. No on-going verification tests are performed.
- 3. Unless otherwise specified, parameters are initial values.
- 4. Maximum rated gate voltage = 15 V_{dc}.
- 5. Unless otherwise specified, relays will be supplied with gold-plated leads.
- 6. The slash and character appearing after the slash are not marked on the relay.



SERIES 116C OUTLINE DIMENSIONS

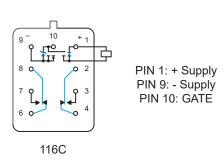




Dimensions: in. (mm)

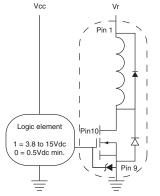
(Viewed From Terminals)

SCHEMATIC DIAGRAMS



TYPICAL CMOS INTERFACE CIRCUIT

DC Logic Voltage Supply



Notes: Logic 1 activates the relay. Logic 0 de-activates the relay. Vcc = logic bias power. Vr = coil energization voltage.



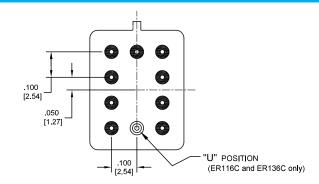
APPENDIX A: Spacer Pads

Pad designation and bottom view dimensions	Height	For use with the following:	Dim. H Max.
.156 [3.96] (REF)		122C, A152	.320 (8.13)
000	Dim H MAX	ER116C, J116C	.300 (7.62)
256 [6.5] (REF)	 	ER136C, J136C	.400 (10.16)
1000		RF180	.325 (8.25)
"M9"Spacer Pad for Centigrid®		A150	.305 (7.75)

Notes

- 1. Spacer pad material: Polyester film.
- 2. To specify an "M9" spacer pad, refer to the mounting variants portion of the part numbering example in the applicable datasheet.
- 3. Dimensions are in inches (mm).
- 4. Unless otherwise specified, tolerance is ± .010" (.25 mm).
- 5. Add 10 m Ω to the contact resistance shown in the datasheet.
- 6. Add 0.01 oz. (0.25 g) to the weight of the relay assembly shown in the datasheet.

APPENDIX A: Ground Pin Positions



Centigrid® Relays:

RF180, ER116C, 122C, ER136C

- O Indicates ground pin position
- Indicates glass insulated lead position
- Indicates ground pin or lead position depending on relay type

NOTES

- 1. Terminal views shown
- 2. Dimensions are in inches (mm)
- 3. Tolerances: ± .010 (±.25) unless otherwise specified
- 4. Ground pin positions are within .015 (0.38) dia. of true position
- 5. Ground pin head dia., 0.035 (0.89) ref: height 0.010 (0.25) ref.
- 6. Lead dia. 0.017 (0.43) nom.